

2SC4140

Silicon NPN Triple Diffused Planar Transistor (High Voltage and High Speed Switching Transistor)

Application : Switching Regulator and General Purpose

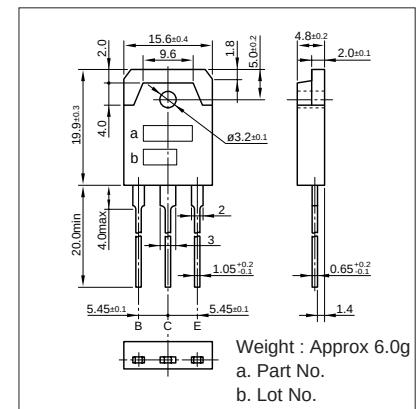
Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit
VCBO	500	V
VCEO	400	V
VEBO	10	V
Ic	18(Pulse36)	A
IB	6	A
Pc	130(Tc=25°C)	W
Tj	150	°C
Tstg	-55 to +150	°C

Electrical Characteristics (Ta=25°C)

Symbol	Conditions	Ratings	Unit
ICBO	VCB=500V	100max	μA
IEBO	VEB=10V	100max	μA
V(BR)CEO	Ic=25mA	400min	V
hFE	VCE=4V, Ic=10A	10 to 30	
VCE(sat)	Ic=10A, IB=2A	0.5max	V
VBE(sat)	Ic=10A, IB=2A	1.3max	V
fr	VCE=12V, IE=-2.0A	10typ	MHz
COB	VCB=10V, f=1MHz	165typ	pF

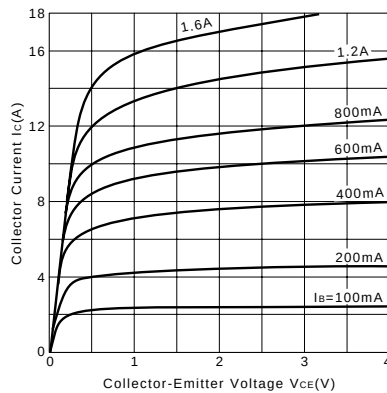
External Dimensions MT-100(TO3P)



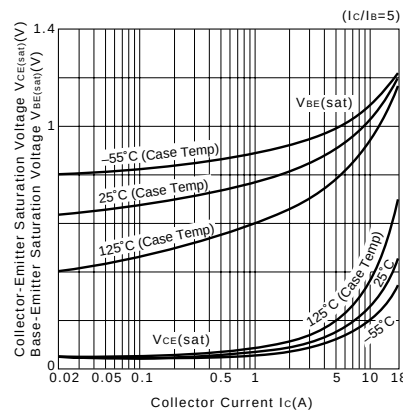
Typical Switching Characteristics (Common Emitter)

VCC (V)	RL (Ω)	Ic (A)	VBB1 (V)	VBB2 (V)	IB1 (A)	IB2 (A)	ton (μs)	tstg (μs)	tf (μs)
200	20	10	10	-5	1	-2	1max	3max	0.5max

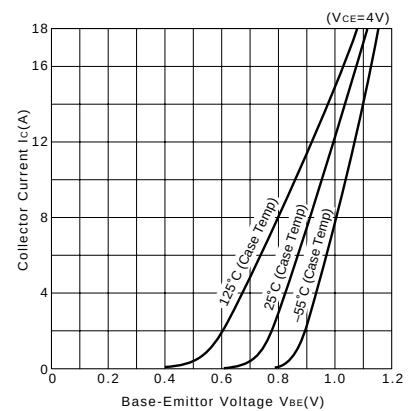
Ic-VCE Characteristics (Typical)



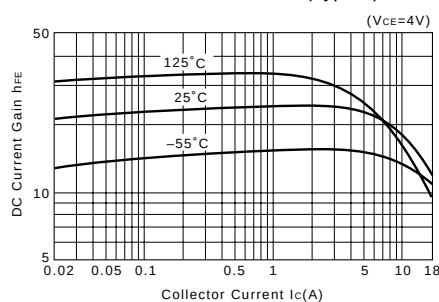
VCE(sat), VBE(sat)-Ic Temperature Characteristics (Typical)



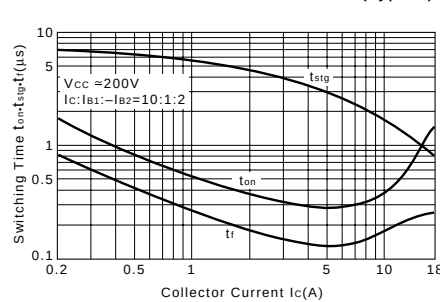
Ic-VBE Temperature Characteristics (Typical)



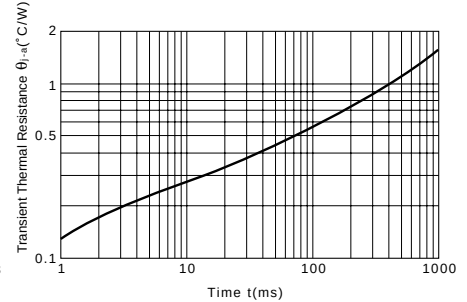
hFE-Ic Characteristics (Typical)



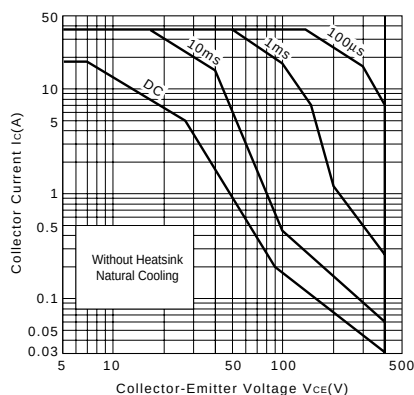
ton, tstg, tr-Ic Characteristics (Typical)



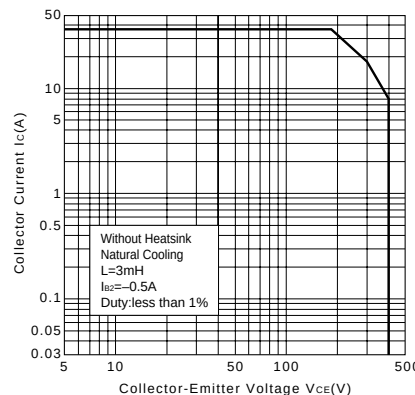
θJA-t Characteristics



Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating

